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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Naoto HORIGUCHI et al.**

Group Art Unit: **2811**

Serial No.: **09/726,386**

Examiner: **Thien F. TRAN**

Filed: **December 1, 2000**

Confirmation No.: **1274**

For: **SEMICONDUCTOR MEMORY WITH FLOATING GATE TYPE FET**

Attorney Docket No.: **001497**

Customer Number: **38834**

AMENDMENT UNDER 37 C.F.R. §1.312

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

June 8, 2004

Sir:

Applicants received a Notice of Allowance dated **April 23, 2004** in connection with the above-identified application. It is respectfully requested that the following amendment be made to the claims of this application:

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 8 of this paper.